# **HEF4050B**

# Hex non-inverting buffers Rev. 05 — 11 November 2008

Product data sheet

### 1. General description

The HEF4050B provides six non-inverting buffers with high current output capability suitable for driving TTL or high capacitive loads. Since input voltages in excess of the buffers' supply voltage are permitted, the buffers may also be used to convert logic levels of up to 15 V to standard TTL levels. Their guaranteed fan-out into common bipolar logic elements is shown in Table 3.

It operates over a recommended V<sub>DD</sub> power supply range of 3 V to 15 V referenced to V<sub>SS</sub> (usually ground). Unused inputs must be connected to  $V_{\text{DD}},\,V_{\text{SS}},$  or another input. It is also suitable for use over the industrial (-40 °C to +85 °C) temperature range.

#### 2. Features

- Accepts input voltages in excess of the supply voltage
- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Operates across the full industrial temperature range -40 °C to +85 °C
- Complies with JEDEC standard JESD 13-B
- ESD protection:
  - HBM JESD22-A114E exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V

# 3. Applications

- LOCMOS (Local Oxidation CMOS) to DTL/TTL converter
- HIGH sink current for driving two TTL loads
- HIGH-to-LOW level logic conversion

# Ordering information

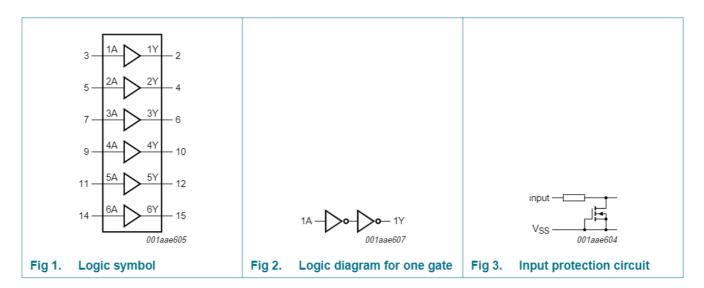
#### Table 1. **Ordering information**

All types operate from -40 °C to +85 °C.

Type number	Package							
	Name	Description	Version					
HEF4050BP	DIP16	plastic dual in-line package; 16-leads (300 mil)	SOT38-4					
HEF4050BT	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1					

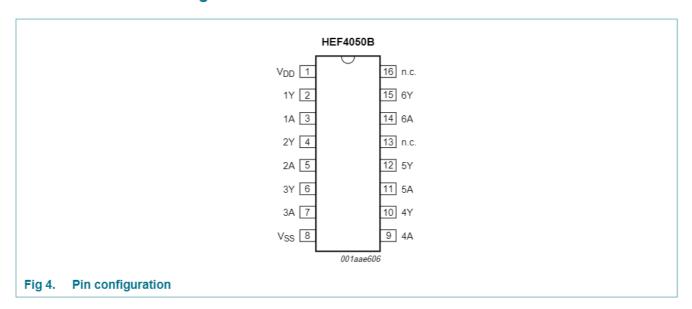


# 5. Functional diagram



# 6. Pinning information

### 6.1 Pinning



# 6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
$V_{DD}$	1	supply voltage
1Y to 6Y	2, 4, 6, 10, 12, 15	output

Table 2. Pin description ... continued

Symbol	Pin	Description
1A to 6A	3, 5, 7, 9, 11, 14,	input
$V_{SS}$	8	ground supply voltage
n.c.	13, 16	not connected

# 7. Functional description

Table 3. Guaranteed fan-out

Driven element	Guaranteed fan-out
Standard TTL	2
74 LS	9
74 L	16

# 8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DD}$	supply voltage		-0.5	+18	V
$V_{I}$	input voltage		-0.5	$V_{DD} + 0.5$	V
$I_{I/O}$	input/output current		-	10	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>amb</sub>	ambient temperature		-40	+85	°C
P <sub>tot</sub>	total power dissipation	$T_{amb}$ –40 °C to +85 °C			
		DIP16 package	[1] _	750	mW
		SO16 package	[2] -	500	mW
Р	power dissipation	per output	-	100	mW

<sup>[1]</sup> For DIP16 package:  $P_{tot}$  derates linearly with 12 mW/K above 70 °C.

# 9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DD}$	supply voltage		3	15	V
$V_{I}$	input voltage		0	$V_{DD}$	V
T <sub>amb</sub>	ambient temperature	in free air	-40	+85	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{DD}$ = 5 $V$	-	3.75	ns/V
		V <sub>DD</sub> = 10 V	-	0.5	ns/V
		V <sub>DD</sub> = 15 V	-	0.08	ns/V

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<sup>[2]</sup> For SO16 package: Ptot derates linearly with 8 mW/K above 70 °C.

### 10. Static characteristics

Table 6. Static characteristics

 $V_{SS}$  = 0 V;  $V_{I}$  =  $V_{SS}$  or  $V_{DD}$  unless otherwise specified.

Symbol	Parameter	Conditions	itions V <sub>DD</sub>	T <sub>amb</sub> =	-40 °C	T <sub>amb</sub> =	25 °C	T <sub>amb</sub> =	85 °C	Unit
				Min	Max	Min	Max	Min	Max	
$V_{\text{IH}}$	HIGH-level input voltage	I <sub>O</sub>   < 1 ∝A	5 V	3.5	-	3.5	-	3.5	-	V
			10 V	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	V
$V_{IL}$	LOW-level input voltage	I <sub>O</sub>   < 1 ∝A	5 V	-	1.5	-	1.5	-	1.5	V
			10 V	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	V
$V_{OH}$	HIGH-level output voltage	I <sub>O</sub>   < 1 ∝A	5 V	4.95	-	4.95	-	4.95	-	V
			10 V	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	V
$V_{OL}$	LOW-level output voltage	I <sub>O</sub>   < 1 ∝A	5 V	-	0.05	-	0.05	-	0.05	V
			10 V	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	V
$I_{OH}$	HIGH-level output current	$V_O$ = 2.5 $V$	5 V	-1.7	-	-1.4	-	-1.1	-	mA
		$V_O$ = 4.6 $V$	5 V	-0.52	-	-0.44	-	-0.36	-	mA
		$V_O = 9.5 V$	10 V	-1.3	-	-1.1	-	-0.9	-	mΑ
		$V_O$ = 13.5 $V$	15 V	-3.6	-	-3.0	-	-2.4	-	mΑ
$I_{OL}$	LOW-level output current	$V_O = 0.4 V$	4.75 V	3.5	-	2.9	-	2.3	-	mΑ
		$V_O = 0.5 V$	10 V	12.0	-	10.0	-	8.0	-	mA
		$V_O = 1.5 V$	15 V	24.0	-	20.0	-	16.0	-	mA
I	input leakage current		15 V	-	±0.3	-	±0.3	-	±1.0	σA
$I_{DD}$	supply current	I <sub>O</sub> = 0 A	5 V	-	4.0	-	4.0	-	30	σA
			10 V	-	8.0	-	8.0	-	60	σA
			15 V	-	16.0	-	16.0	-	120	αA
$C_{I}$	input capacitance			-	-	-	7.5	-	-	pF

# 11. Dynamic characteristics

Table 7. Dynamic characteristics

 $V_{SS}$  = 0 V;  $T_{amb}$  = 25 °C; for test circuit see Figure 6; unless otherwise specified.

Symbol	Parameter	Conditions	$V_{DD}$	Extrapolation formula	Min	Тур	Max	Unit
11112	HIGH to LOW	nA to nY;	5 V	11 26 ns + (0.18 ns/pF)C <sub>L</sub>	-	35	70	ns
	propagation delay	see Figure 5	10 V	16 ns + (0.08 ns/pF)C <sub>L</sub>	-	20	35	ns
			15 V	12 ns + $(0.05 \text{ ns/pF})C_L$	-	15	30	ns
$t_{\text{PLH}}$	LOW to HIGH	ropagation delay see Figure 5 10 V	5 V	11 28 ns + $(0.55 \text{ ns/pF})C_L$	-	55	110	ns
	propagation delay		10 V	14 ns + (0.23 ns/pF)C <sub>L</sub>	-	25	55	ns
			15 V	12 ns + (0.16 ns/pF)C <sub>L</sub>	-	20	40	ns

Table 7. Dynamic characteristics ... continued

 $V_{SS}$  = 0 V;  $T_{amb}$  = 25 °C; for test circuit see Figure 6; unless otherwise specified.

Symbol	Parameter	Conditions	$V_{DD}$	Extrapolation formula	Min	Тур	Max	Unit
t <sub>THL</sub> HIGH to LOW		GH to LOW see Figure 5 V		11 7 ns + $(0.35 \text{ ns/pF})C_L$	-	25	50	ns
output transition time		10 V	$3 \text{ ns} + (0.14 \text{ ns/pF})C_L$	-	10	20	ns	
		1	15 V	$2 \text{ ns} + (0.09 \text{ ns/pF})C_L$	-	7	14	ns
t <sub>TLH</sub> LOW to HIGH			5 V	10 ns + (1.00 ns/pF)C <sub>L</sub>	-	60	120	ns
output transition time		10 V	9 ns + $(0.42 \text{ ns/pF})C_L$	-	30	60	ns	
		15 V	15 V	6 ns + $(0.28 \text{ ns/pF})C_L$	-	20	40	ns

<sup>[1]</sup> The typical values of the propagation delay and transition times are calculated from the extrapolation formulas shown (C<sub>L</sub> in pF).

Table 8. Dynamic power dissipation P<sub>D</sub>

 $P_D$  can be calculated from the formulas shown.  $V_{SS}$  = 0 V;  $t_r$  =  $t_f \le$  20 ns;  $T_{amb}$  = 25 °C.

Symbol	Parameter	$V_{DD}$	Typical formula for P <sub>D</sub> (∞W)	where:
$P_D$	dynamic power	5 V	$P_D = 3800  \cdot  f_i + \Sigma (f_0  \cdot  C_L)  \cdot  V_{DD}{}^2$	$f_i$ = input frequency in MHz,
dissipation	10 V	$P_D = 11600 \cdot f_i + \Sigma (f_0 \cdot C_L) \cdot V_{DD}^2$	f <sub>0</sub> = output frequency in MHz,	
		15 V	$P_D = 65900 \cdot f_i + \Sigma (f_0 \cdot C_L) \cdot V_{DD}^2$	$C_L$ = output load capacitance in pF, $V_{DD}$ = supply voltage in V, $\Sigma(C_L \cdot f_0)$ = sum of the outputs.

### 12. Waveforms

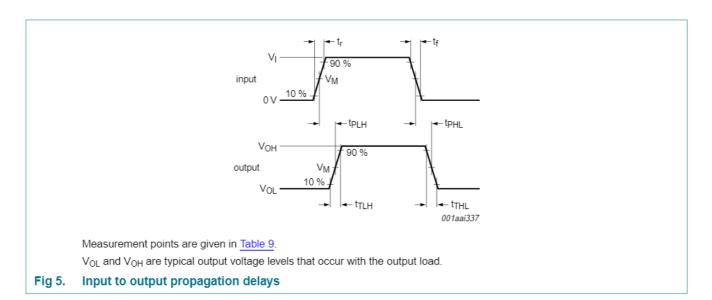
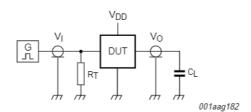


Table 9. Measurement points

Input	Output	
$V_{M}$	V <sub>I</sub>	V <sub>M</sub>
0.5V <sub>DD</sub>	0 V to V <sub>DD</sub>	0.5V <sub>DD</sub>

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Test data is given in Table 10.

Definitions for test circuit:

C<sub>L</sub> = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator.

Fig 6. Test circuit for switching times

#### Table 10. Test data

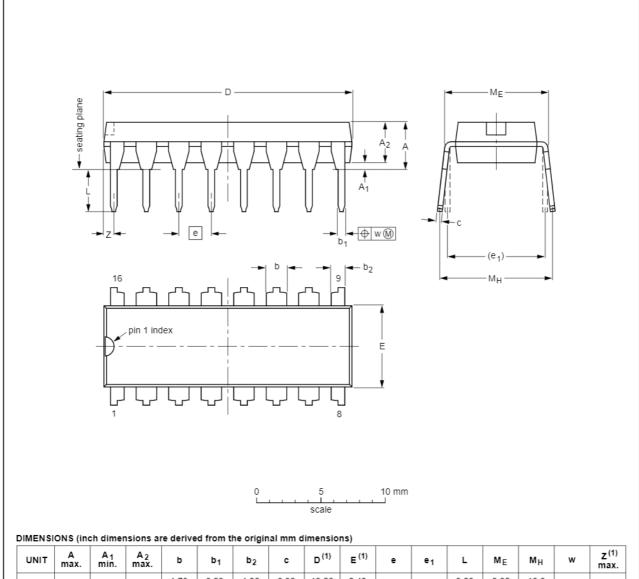
Supply voltage	Input	Load		
	VI	V <sub>M</sub>	t <sub>r</sub> , t <sub>f</sub>	CL
5 V to 15 V	$V_{DD}$	0.5V <sub>I</sub>	≤ 20 ns	50 pF

# 13. Package outline

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4

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	max.	1111111.	max.			_							_			max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.03

#### Note

Product data sheet

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

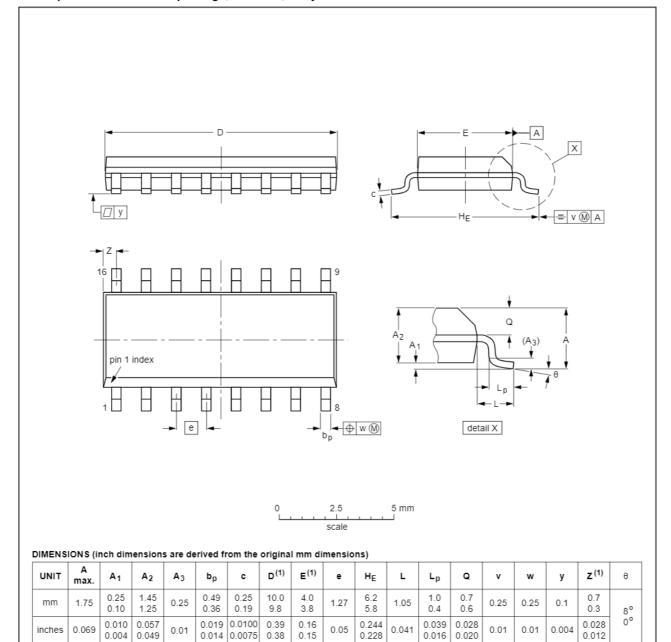
OUTLINE		REFER	EUROPEAN	ICCUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT38-4						<del>95-01-14</del> 03-02-13

Package outline SOT38-4 (DIP16) Fig 7.

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#### SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



# Note

Product data sheet

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	100115 5455		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT109-1	076E07	MS-012				<del>99-12-27</del> 03-02-19

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Fig 8. Package outline SOT109-1 (SO16)

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Hex non-inverting buffers

# 14. Abbreviations

#### Table 11. Abbreviations

Acronym	Description
DUT	Device Under Test
DTL	Diode Transistor Logic
ESD	ElectroStatic Discharge
HBM	Human Body Model
LOCMOS	Local Oxidation CMOS
MM	Machine Model
TTL	Transistor Transistor Logic

# 15. Revision history

#### Table 12. Revision history

Product data sheet

	•			
Document ID Release date		Data sheet status	Change notice	Supersedes
HEF4050B_5 20081111		Product data sheet	-	HEF4050B_4
Modifications:	Section 1 "	F <sub>amb</sub> changed to 85 °C and 1 General description" temper "Static characteristics" I <sub>DD</sub> , I	ature range statement r	
HEF4050B_4	20080702	Product data sheet	-	HEF4050B_CNV_3
HEF4050B_CNV_3	19950101	Product specification	-	HEF4050B_CNV_2
HEF4050B_CNV_2	19950101	Product specification	-	-

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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